Icemos Technology Ltd Product Specification 1000.737301 Issue Date 25 May 2023 16:20:20

Part Number	Customer	

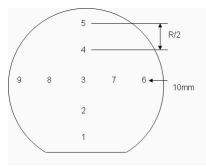
Category	Parameter		Specification	<b>Measurement Method</b>
OverallWafer	1.0	Diameter	150.00 +/- 0.20 mm	
	2.0	Primary Flat Orientation	{110} +/- 1.0 degree	Wafer Vendor
	3.0	Primary Flat Length	57.50 +/- 2.50 mm	Wafer Vendor
	4.0	Secondary Flat Orientation	none	Wafer Vendor
	5.0	Overall Thickness	430.50 +/- 6.00 μm	ADE, 100%
	6.0	Total Thickness Variation (TTV)	<3.00μm	Guaranteed by Process
	7.0	Bow	<60.00μm	ADE to ASTM F534, 100%
	8.0	Warp	<60.00μm	ADE to ASTM F534, 100%
	9.0	Edge Chips	0	Bright Light, 100%
	10.0	Edge Exclusion	5mm	
	11.0	Bond Process	Fusion Bonding	Guaranteed by Process
HandleSilicon	12.0	Handle Growth Method	CZ	Wafer Vendor
	13.0	Handle Orientation	{100} +/- 0.5 degree	Wafer Vendor
	14.0	Handle Thickness	400.00 +/- 5.00 μm	ADE, 100%
	15.0	Handle Doping Type	Р	Wafer Vendor
	16.0	Handle Dopant	Boron	Wafer Vendor
	17.0	Handle Resistivity	1~20 Ohmcm	Wafer Vendor
	18.0	Backside Finish	Polished with oxide, lasermark, and light handling marks	Guaranteed by process
BuriedOxide	19.0	Oxide Type	Thermal	
	20.0	Oxide Thickness	5,000.00 +/- 250.00 A	Nanospec centre point, 4%
	21.0	Oxide formed on	Handle or/and Device	
DeviceSilicon	22.0	Device Growth Method	CZ	Wafer Vendor
	23.0	Device Orientation	{100} +/- 0.5 degree	Wafer Vendor
	24.0	Nominal Thickness	30.00 +/- 0.50 μm	Filmetrics 9pts, 100% (note3)
	25.0	Distance to device silicon edge from wafer edge	< 2mm	Typical by Process
	26.0	Device Doping Type	N	Wafer Vendor
	27.0	Device Dopant	Phosphorous	Wafer Vendor
	28.0	Device Resistivity	0.4~1.15 Ohmem	Wafer Vendor
	29.0	Surface Voids	None	Bright Light, 100% (note2)
	30.0	Haze	None	Bright Light, 100% (note2)
	31.0	Scratches	none on the front-side	Bright Light, 100% (note2)

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Part Number		Customer		
Category	Parameter	Specification	Measurement Method	
Shipping Details	Wafer per box :	Max 25		
	Packaging:	Taped Polypropylene Wafer Box Empak, Ultrapak, 150.00mm Antistatic Double Bagging		
	Lot Shipment Data	Device Thickness Bow / Warp Data Handle and SOI Thickness		
Explanatory Notes	1. Microscope inspec	tion performed using microscope scan as below. 5x objective.		
		pections performed exclude all wafer area outside the edge exclusio	on defined in Overall	

Wafer, Edge Exclusion. High intensity bright lamp inspection as per ASTM F523.

3. 9 point measurement are as shown in the diagram below:



Additional Information